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FIG. 1α

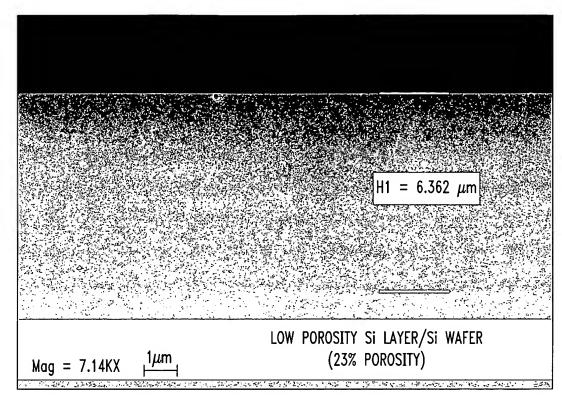


FIG. 1b

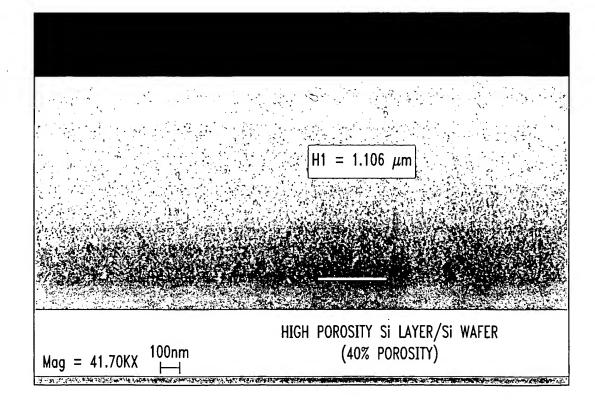
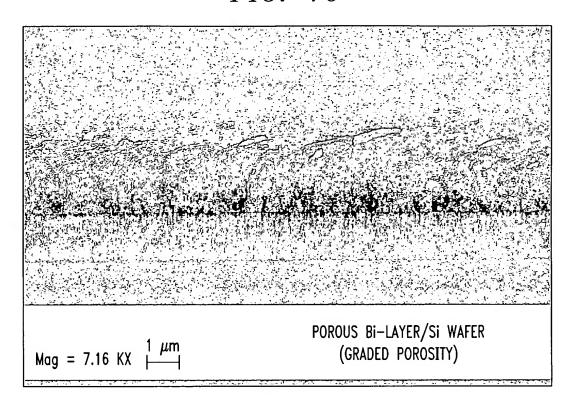


FIG. 1c



 $FIG.\ \mathcal{Z}$ substrate based on use of the porous-si layer and subsequent regrowth of epi-si layer to create soi wafers

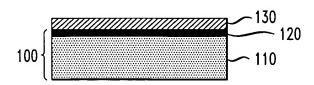
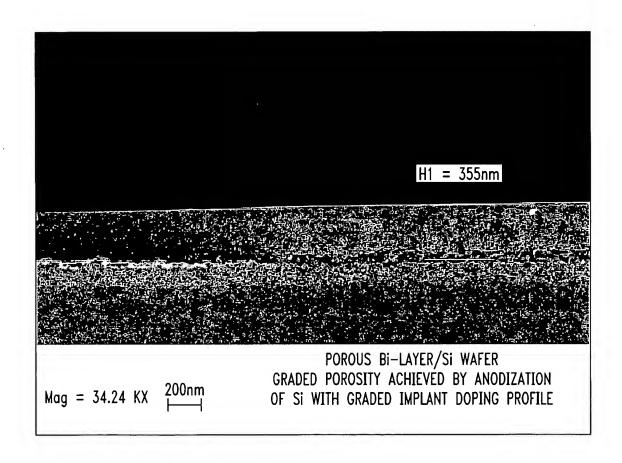
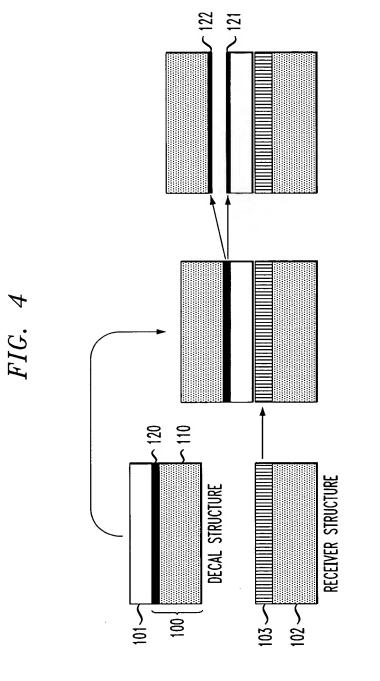


FIG. 3





#1 STEP: BUILD OF DECAL
AND RECEIVER STRUCTURES
AND RECEIVER STRUCTURES

#3 STEP: RELEASE OF CARRIER SUBSTRATE VIA PEELING

